

1. Description

The DMP6185SK3-13(ES) is P-Channel enhancement MOS Field Effect Transistor. Using advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product DMP6185SK3-13(ES) is Pb-free.

2. Features

- -60V, $R_{DS(ON)}=80m\Omega(Typ.) @V_{GS}=-10V$
- $R_{DS(ON)}=100m\Omega(Typ.) @V_{GS}=-4.5V$
- High density cell design for low $R_{DS(on)}$
- Material: Halogen free
- Reliable and rugged
- Avalanche Rated
- Low leakage current

3. Applications

- PWM applications
- Load switch
- Power management in portable/desktop PCs
- DC/DC conversion

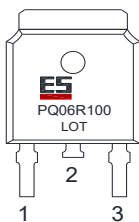
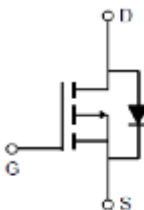
100% UIS TESTED

4. Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel Size
DMP6185SK3-13(ES)	TO-252	PQ06R100/LOT	Halogen free	Tape & Reel	2,500 PCS	UL 94V-0	13 inches

Table-1 Ordering information

5. Pin Configuration and Functions

Pin	Function	Outline	Circuit Diagram
1	Gate	Note b 	
3	Source		
2	Drain		

6. Specification

Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		BV_{DSS}	-60	V
Gate-Source Voltage		V_{GS}	±20	V
Continuous Drain Current	$T_C=25^{\circ}C$	I_D	-14	A
	$T_C=100^{\circ}C$		-8.4	
Total Power Dissipation	$T_C=25^{\circ}C$	P_D	36	W
Pulsed Drain Current		I_{DM}	-56	A
Avalanche Current, Single Pulsed(L=0.5mH)		I_{AS}	-8.5	A
Avalanche Energy, Single Pulsed ^a		E_{AS}	18	mJ
Operating Junction Temperature		T_J	-55 to 150	°C
Storage Temperature Range		T_{stg}	-55 to 150	°C

Thermal resistance ratings

Single Operation			
Parameter	Symbol	Value	Unit
Junction-to-Case Thermal Resistance	$R_{\theta JC}$	3.5	°C/W

Notes:

a: EAS condition: $T_J=25^{\circ}C$, $V_{DD}=-30V$, $V_{GS}=-10V$, $L=0.5mH$, $R_G=25\Omega$.

b: This diagram is only an electrical schematic, and the actual pin size is based on POD.

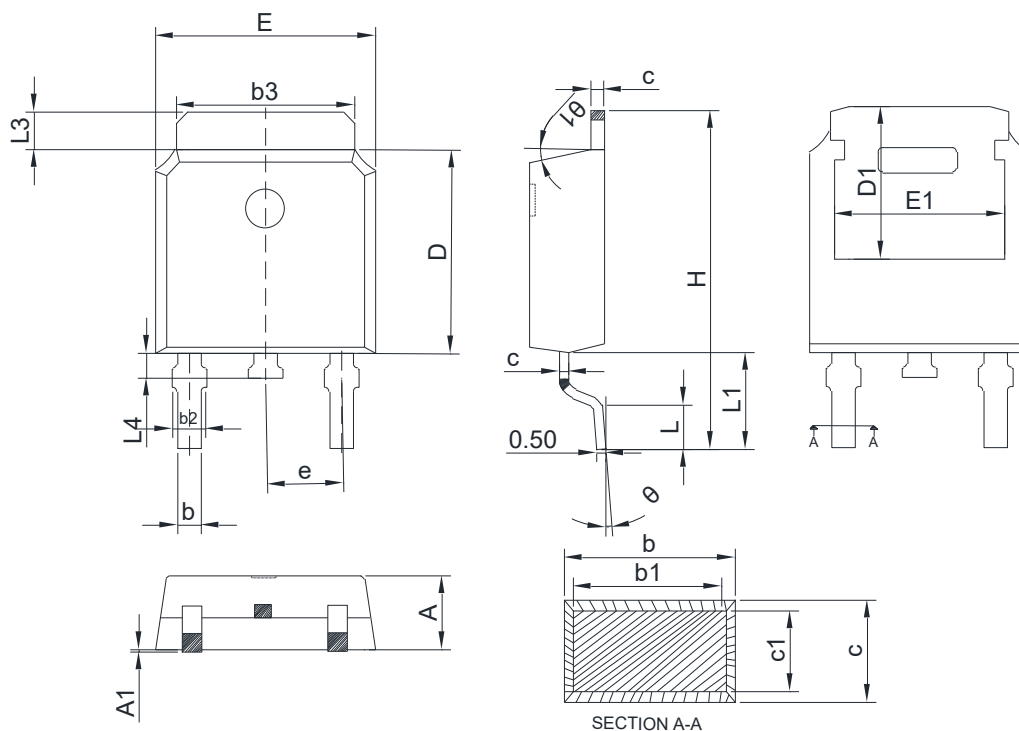
Electrical Characteristics

At TA = 25°C unless otherwise specified

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-60			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} =0V, V _{DS} =-60V			-1	uA
Gate-to-source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V			±100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{GS} =V _{DS} , I _D =-250uA	-1.1	-1.7	-2.4	V
Drain-to-source On-resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-2.5A		80	104	mΩ
		V _{GS} =-4.5V, I _D =-2A		100	130	
CHARGES, CAPACITANCES AND GATE RESISTANCE						
Input Capacitance	C _{ISS}	V _{GS} =0V, V _{DS} =-25V f=1MHz		978		pF
Output Capacitance	C _{OSS}			51		
Reverse Transfer Capacitance	C _{RSS}			39		
Total Gate Charge	Q _{G(TOT)}	V _{GS} =0 to -10V, V _{DS} =-30V, I _D =-5A		18		nC
Gate-to-Source Charge	Q _{GS}			4		
Gate-to-Drain Charge	Q _{GD}			5.2		
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	t _{d(ON)}	V _{GS} =-10V, V _{DD} =-30V I _D =-5A, R _G =3Ω		9		ns
Rise Time	t _r			15		
Turn-Off Delay Time	t _{d(OFF)}			33		
Fall Time	t _f			12		
BODY DIODE CHARACTERISTICS						
Forward Voltage	V _{SD}	V _{GS} =0V, I _{SD} =-2.5A			-1.2	V

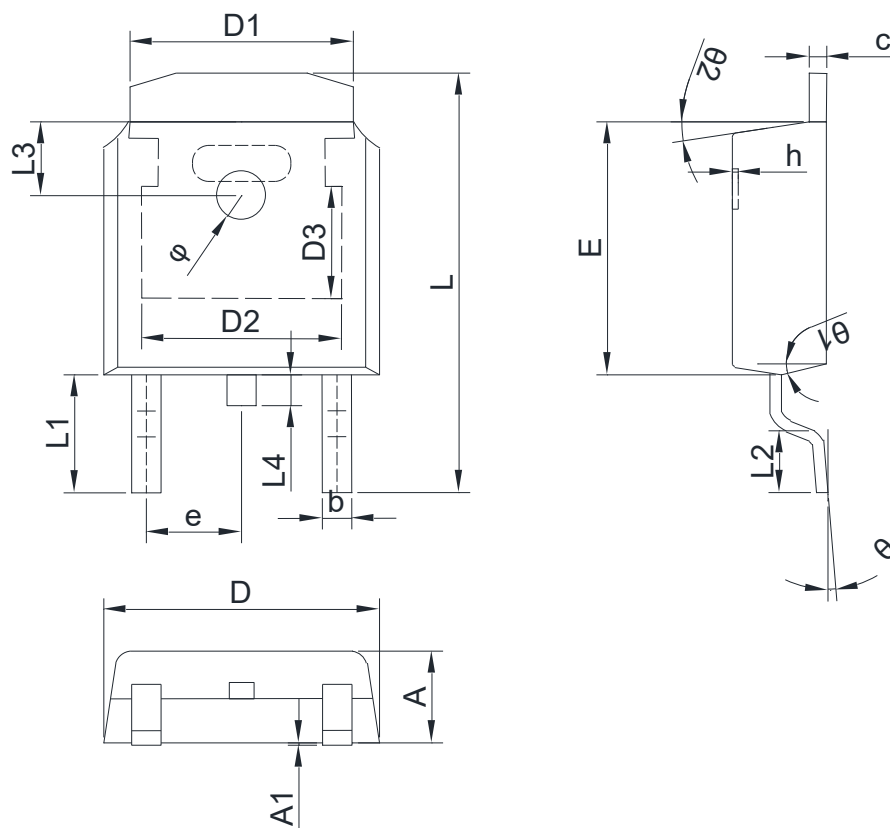
8. Dimension (TO-252)

POD A(Q)



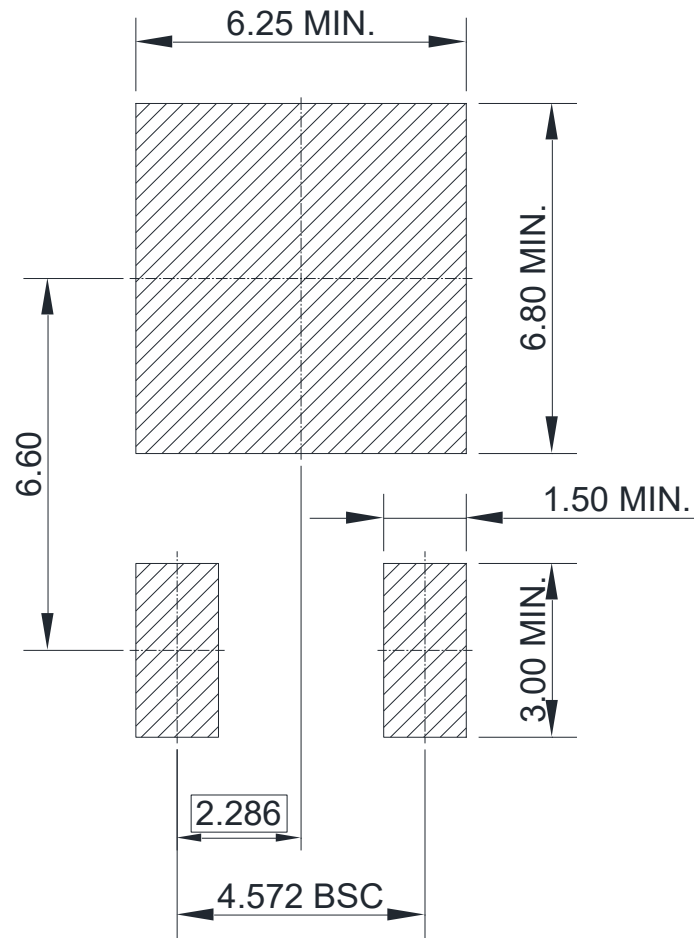
COMMON DIMENSIONS CUNITS MEASURE=MILLIMETER							
SYMBOL	MIN	TYP	MAX	SYMBOL	MIN	TYP	MAX
A	2.20	2.30	2.40	D1	5.21	-	-
A1	0.00	-	0.12	E	6.50	6.60	6.70
b	0.65	-	0.89	E1	4.32	-	-
b1	0.64	0.76	0.79	H	9.70	9.95	10.20
b2	0.76	0.86	1.10	L	1.40	1.50	1.60
b3	5.20	5.33	5.46	L1	2.84REF		
c	0.48	-	0.60	e	2.29BSC		
c1	0.47	0.51	0.55	θ	0°	-	10°
D	6.00	6.10	6.20	θ1	0°	-	15°
L3	0.90	-	1.27	L4	0.60	0.80	1.00

POD B(X)



COMMON DIMENSIONS CUNITS MEASURE=MILLIMETER							
SYMBOL	MIN	TYP	MAX	SYMBOL	MIN	TYP	MAX
A	2.200	2.300	2.400	h	0.000	0.100	0.200
A1	0.000		0.127	L	9.900	10.100	10.300
b	0.640	0.690	0.740	L1	2.888 REF		
c(电镀后)	0.460	0.520	0.580	L2	1.400	1.550	1.700
D	6.500	6.600	6.700	L3	1.600 REF		
D1	5.334 REF			L4	0.600	0.800	1.000
D2	4.826 REF			φ	1.100	1.200	1.300
D3	3.166 REF			θ	0°		8°
E	6.000	6.100	6.200	θ1	9° TYP		
e	2.286 TYP			θ2	9° TYP		

9. Recommended Soldering Footprint



DIMENSIONS: MILLIMETERS

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